### SIC SCHOTTKY DIODE TYPE 2x25A

### **Features**

• High surge current capable

• Temperature independent switching behavior

• Zero reverse recovery current • VDC • High bandwidth

1200 V • **|**F (Tc<135°C) 2×25 A

• Isolation type package

Unipolar rectifier

**Benefits** 

Smaller heat sink

Zero switching loss

• Parallel devices without thermal runaway

Higher efficiency

## **Applications**

Motor drives

Power factor correction

• Switch mode power supplies

Diode snubber

Ev chargers

Automotive

Solar inverters

induction heating

Welding equipment

# **Maximum Ratings**

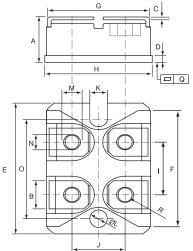
Operating Junction Temperature : -55  $^{\circ}$ C to +175  $^{\circ}$ C

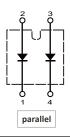
Storage Temperature :  $-55 \,^{\circ}\text{C}$  to  $+175 \,^{\circ}\text{C}$ 

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum DC Blocking Voltage
CSRI2×25-120	1200V	1200V

Maximum Rating	Symbol	Conditions	Value	Unit	
Continuous forward current (per diode)	I <sub>F</sub>	I <sub>F</sub> T <sub>C</sub> =135 °C			
Surge non-repetitive forward current	I <sub>FSM</sub>	$T_{C}$ =25 °C, $t_{p}$ =8.3 ms	200		
sine halfwave (per diode)	1 GIVI	T <sub>C</sub> =150 °C, t <sub>p</sub> =8.3 ms	125	Α	
Non-repetitive peak forward current	I <sub>F,max</sub>	T <sub>C</sub> =25 °C, $t_p$ =10 $\mu$ s	800	00	
(per diode)		$T_{C}$ =150 °C, $t_{p}$ =10 $\mu$ s	500		
Repetitive peak reverse voltage	$V_{RRM}$	T <sub>j</sub> =25 °C	1200	V	
Isolation voltage (between Terminals and Baseplate)	V <sub>iso</sub>	50/60 Hz, t=1min I <sub>ISOL</sub> ≤ 1mA	2500	V	
Mounting torque	M <sub>d</sub>	To heatsink	1.3	Nm	
mounting torquo	·via	To terminal	1.1		







DIMENSIONS						
	INCHES		MM			
	MIN	MAX	MIN	MAX		
Α	0.460	0.483	11.68	12.28		
В	0.307	0.323	7.80	8.20		
С	0.030	0.033	0.75	0.85		
D	0.071	0.081	1.80	2.05		
E	1.488	1.504	37.80	38.20		
F	1.248	1.260	31.70	32.00		
G	0.917	0.957	23.30	24.30		
Н	0.996	0.996 1.008 25		25.60		
- 1	0.579	0.602	14.70	15.30		
J	0.492	0.516	12.50	13.10		
K	0.161	0.169	4.10	4.30		
L	0.161	0.169	4.10	4.30		
M	0.181	0.197 4.60		5.00		
N	0.165	0.181	4.20	4.60		
0	1.181	1.197	30.00	30.40		
Q	-0.002	0.004	-0.05 0.10			
R	M4*8					

### **Electrical Characteristics**, at T<sub>i</sub>=25 °C, unless otherwise specified. (per diode)

Static Characteristics	Symbol	Conditions	Values			
			min.	typ.	max.	Unit
DC blocking voltage	V <sub>DC</sub>		1,200	-	-	
	V <sub>F</sub>	I <sub>F</sub> =25A, T <sub>j</sub> =25 °C	-	1.6	1.8	V
Diode forward voltage	VF	I <sub>F</sub> =25A, T <sub>j</sub> =175 °C	-	2.4	2.9	
	l-	V <sub>R</sub> =1,200V, T <sub>j</sub> =25 °C	-	2.2	109	
Reverse current	I <sub>R</sub>	V <sub>R</sub> =1,200V, T <sub>j</sub> =175 °C	-	140	1,400	$\mu$ A

### AC Characteristics (per diode)

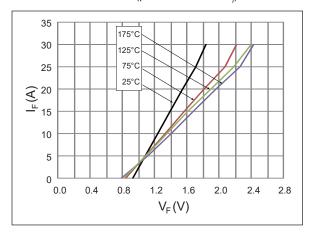
Static Characteristics	Symbol	Conditions	Values			
			min.	typ.	max.	Unit
Total capacitive charge	$Q_{rr}$	V <sub>R</sub> =1,200V, T <sub>j</sub> =25 °C	-	72	-	nC
Total capacitance	С	V <sub>R</sub> =0V, f=1 MHz T <sub>j</sub> =25 °C	-	1,390	-	pF
		V <sub>R</sub> =600V, f=1 MHz T <sub>j</sub> =25 °C	-	138	-	
		V <sub>R</sub> =1,000V, f=1 MHz T <sub>j</sub> =25 °C	-	129	-	

### Thermal Characteristics (per diode)

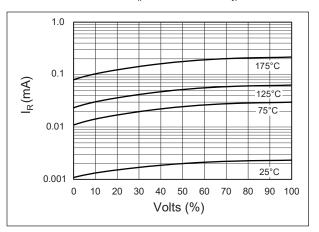
Static Characteristics	Symbol	Values		
Static Characteristics	Symbol	typ.	Unit	
Thermal resistance from junction to case	$R_{ heta JC}$	0.56	°C/W	

#### **Typical Performance**

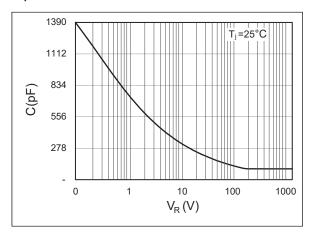
### Forward Characteristics (parameterized on T<sub>i</sub>)



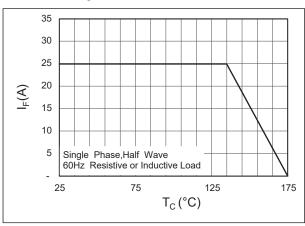
### Reverse Characteristics (parameterized on Tj)



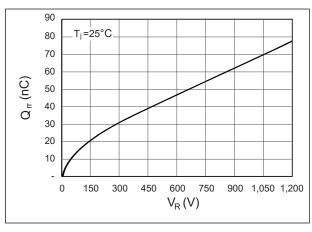
### Capacitance



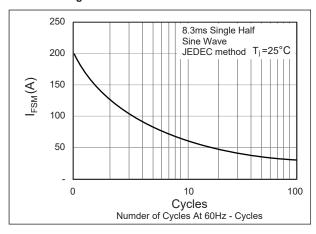
### **Current Derating**



### **Recovery Charge**



### **Forward Surge Current**



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